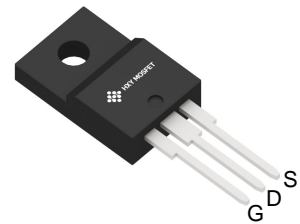




Description

The 16N65F can be used in various power switching circuit for system miniaturization and higher efficiency. The package form is TO-220/TO-220F, which accords with the RoHS standard.

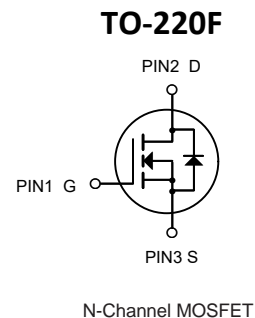


General Features

$V_{DS} = 650V, I_D = 20A$
 $R_{DS(ON)} < 0.47\Omega @ V_{GS}=10V$

Application

- Power switch circuit of adaptor and charger.



Package Marking and Ordering Information

Product ID	Pack	Marking	Units Tube
16N65F	TO-220F	16N65 XXX YYYY	50

Absolute Maximum Ratings@T =25°C(unless otherwise specified)

Symbol	Parameter	Limit	Unit
V_{DSS}	Drain-to-Source Voltage ^[1]	650	V
V_{GSS}	Gate-to-Source Voltage	±30	
I_D	Continuous Drain Current	16	A
$I_D @ T_c=100^{\circ}C$	Continuous Drain Current @ $T_c=100^{\circ}C$	10	
I_{DM}	Pulsed Drain Current at $V_{GS}=10V^{[2]}$	64	
E_{AS}	Single Pulse Avalanche Energy	845	mJ
P_D	Power Dissipation	34	W
T_L T_{PAK}	Maximum Temperature for Soldering Leads at 0.063in (1.6mm) from Case for 10 seconds, Package Body for 10 seconds	300 260	$^{\circ}C$
$T_J \& T_{STG}$	Operating and Storage Temperature Range	-55 to 150	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	3.7	$^{\circ}C/W$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	52	

Caution: Stresses greater than those listed in the "Absolute Maximum Ratings" may cause permanent damage to the device.



Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V _{(BR)DSS}	Drain-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	650	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 650V, V _{GS} = 0V	-	-	1.0	μA
I _{GSS}	Gate-Body Leakage Current	V _{DS} = 0V, V _{GS} = ±30V	-	-	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	2	3	4	V
R _{DS(ON)}	Static Drain-Source ON-Resistance ⁽⁴⁾	V _{GS} = 10V, I _D = 8A	-	0.48	0.62	Ω
C _{iss}	Input Capacitance	V _{GS} = 0V, V _{DS} = 25V, f = 1MHz	-	2747	-	pF
C _{oss}	Output Capacitance		-	224	-	pF
C _{rss}	Reverse Transfer Capacitance		-	27	-	pF
Q _g	Total Gate Charge	V _{GS} = 0 to 10V V _{DS} = 520V, I _D = 16A	-	62	-	nC
Q _{gs}	Gate Source Charge		-	14	-	nC
Q _{gd}	Gate Drain("Miller") Charge		-	24	-	nC
t _{d(on)}	Turn-On DelayTime	V _{GS} = 10V, V _{DD} = 310V I _D = 16A, R _{GEN} = 24Ω	-	38	-	ns
t _r	Turn-On Rise Time		-	52	-	ns
t _{d(off)}	Turn-Off DelayTime		-	176	-	ns
t _f	Turn-Off Fall Time		-	68	-	ns
I _S	Maximum Continuous Drain to Source Diode Forward Current		-	-	16	A
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	64	A
V _{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0V, I _S = 16A	-	-	1.2	V
trr	Body Diode Reverse Recovery Time	I _F = 16A, di/dt = 100A/us	-	476	-	ns
Qrr	Body Diode Reverse Recovery Charge		-	6.9	-	μC

- Notes:
1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.
 2. E_{AS} condition: Starting $T_J = 25^\circ\text{C}$, $V_{DD} = 50\text{V}$, $V_G = 10\text{V}$, $R_G = 25\Omega$, $L = 10\text{mH}$, $I_{AS} = 13\text{A}$
 3. $R_{\theta JA}$ is measured with the device mounted on a minimum recommended pad of 2oz copper FR4 PCB
 4. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 0.5\%$.



Typical Characteristics

Figure 1: Output Characteristics

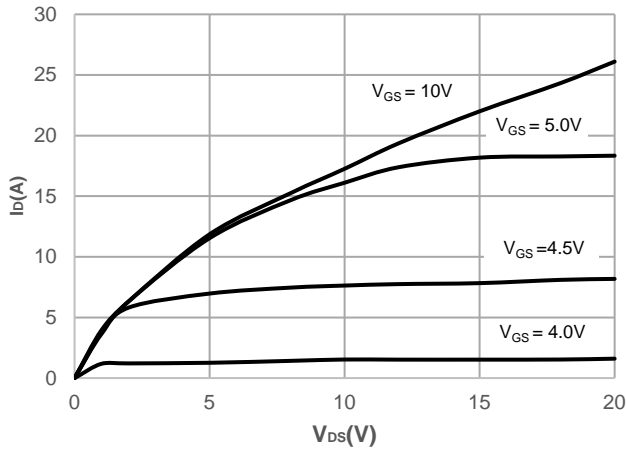


Figure 2: Typical Transfer Characteristics

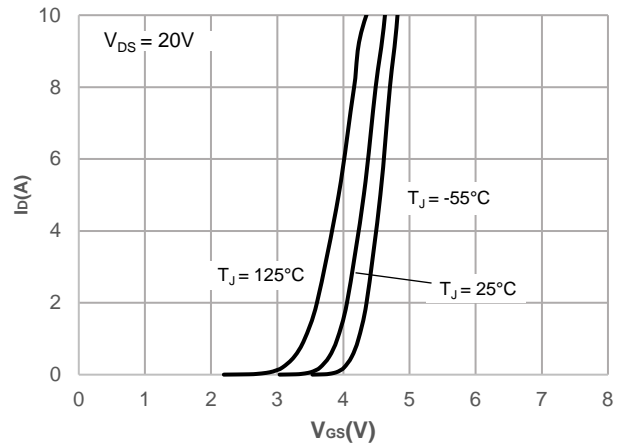


Figure 3: On-resistance vs. Drain Current

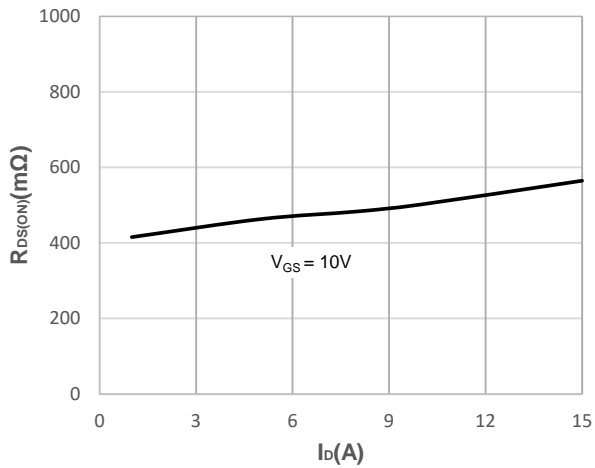


Figure 4: Body Diode Characteristics

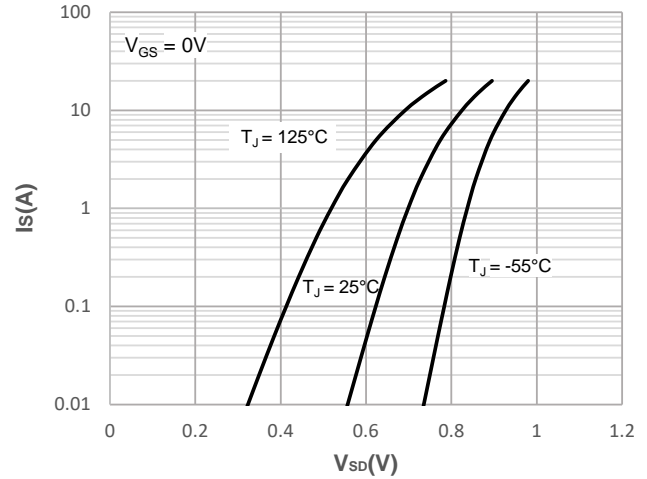


Figure 5: Gate Charge Characteristics

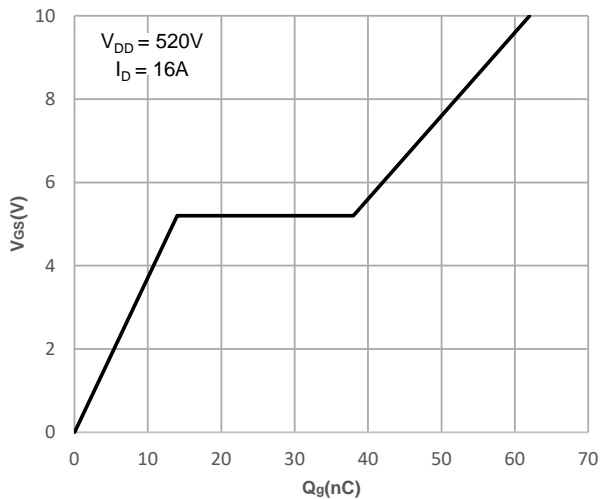


Figure 6: Capacitance Characteristics

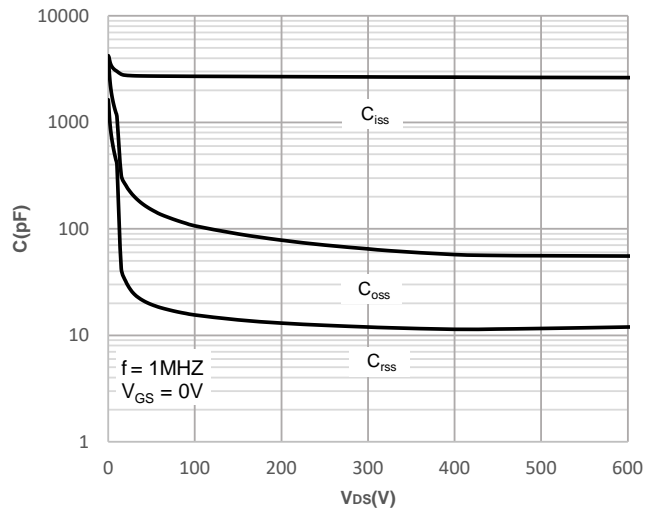




Figure 7: Normalized Breakdown voltage vs. Junction Temperature

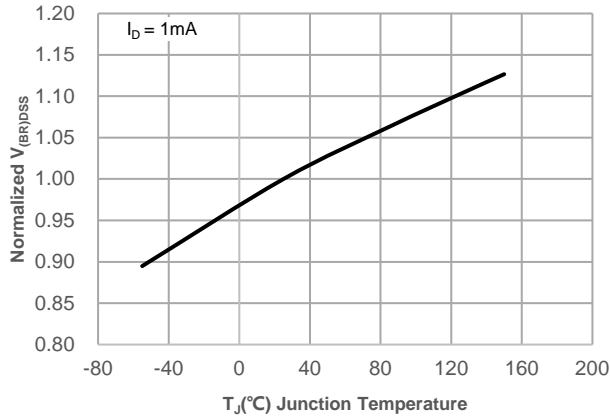


Figure 8: Normalized on Resistance vs. Junction Temperature

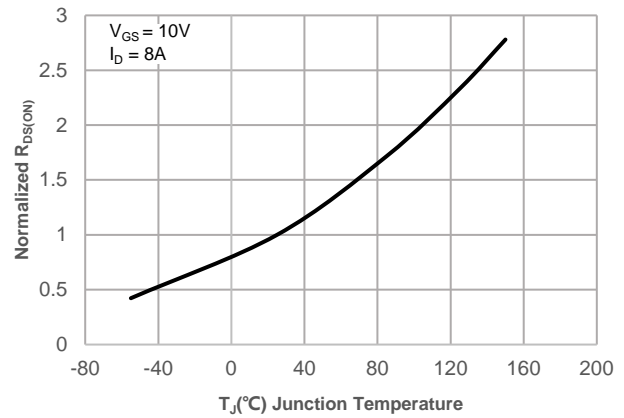


Figure 9: Maximum Safe Operating Area

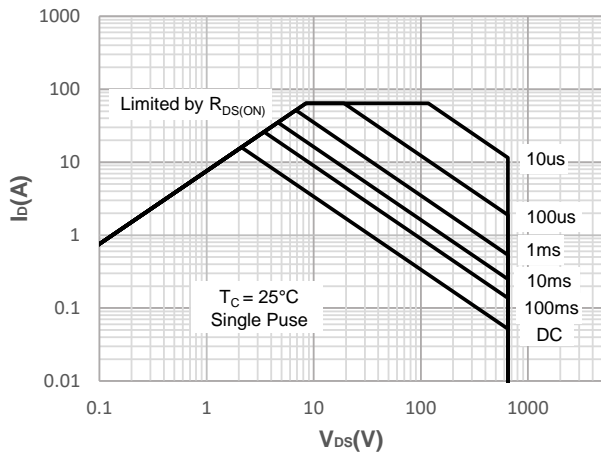


Figure 10: Maximum Continuous Drian Current vs. Case Temperature

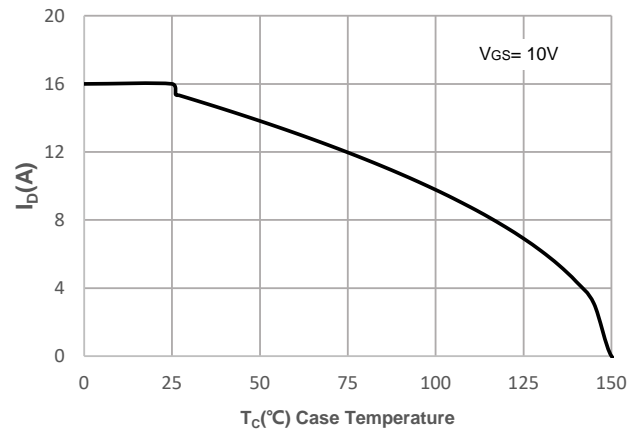


Figure 11: Normalized Maximum Transient Thermal Impedance

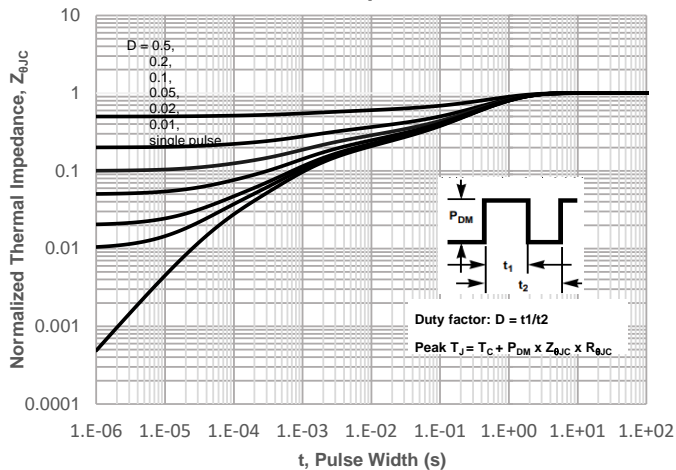
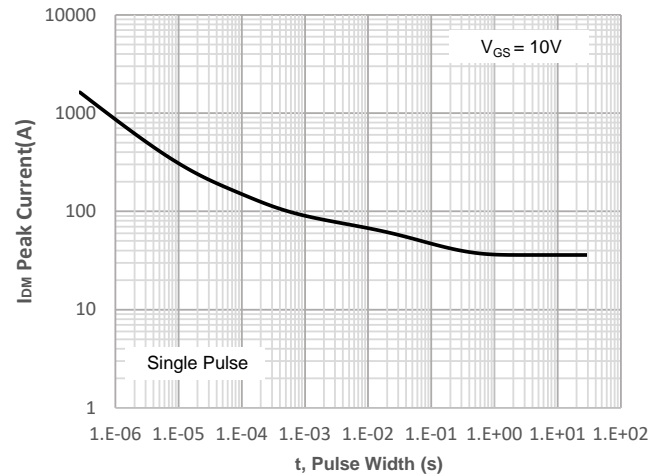


Figure 12: Peak Current Capacity





Test Circuit

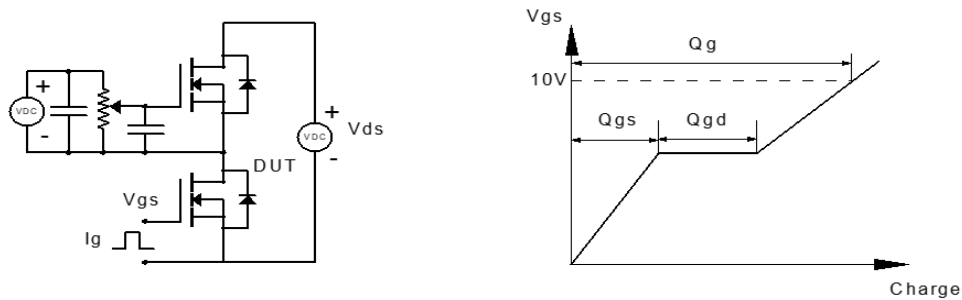


Figure 1: Gate Charge Test Circuit & Waveform

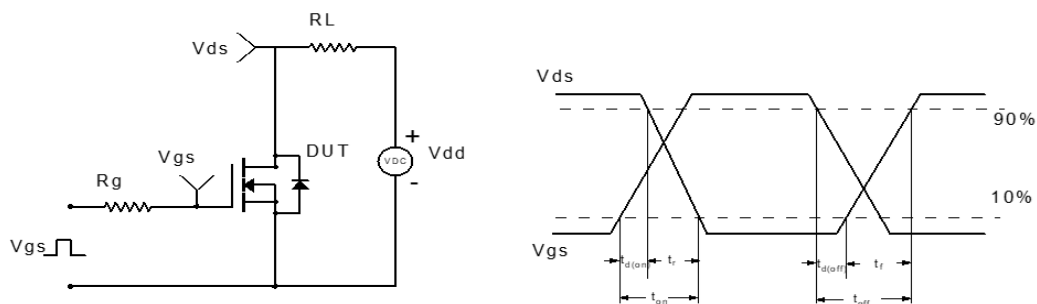


Figure 2: Resistive Switching Test Circuit & Waveform

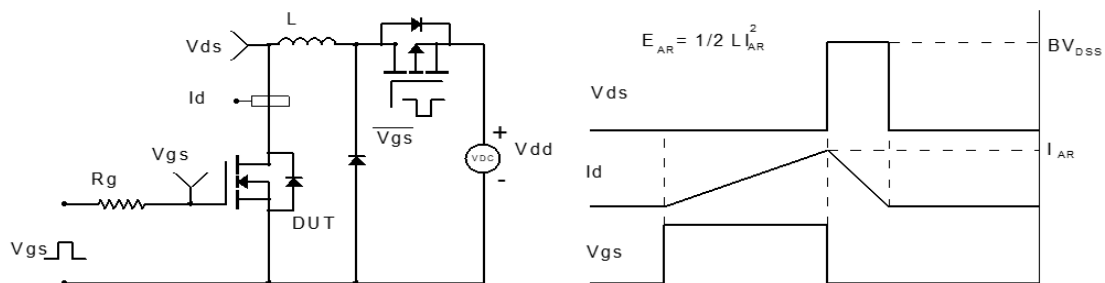


Figure 3: Unclamped Inductive Switching Test Circuit & Waveform

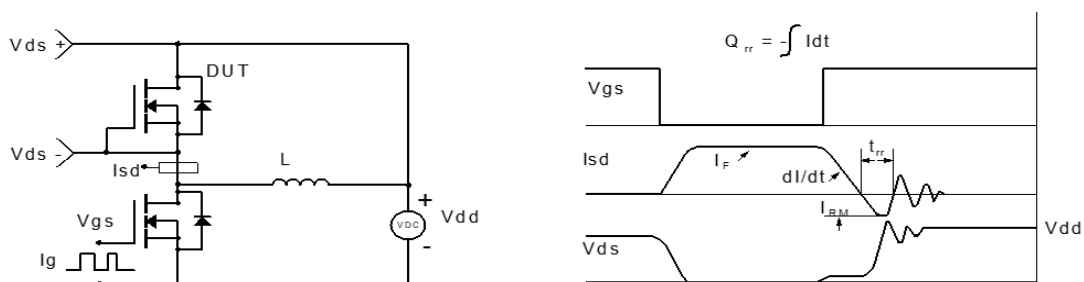
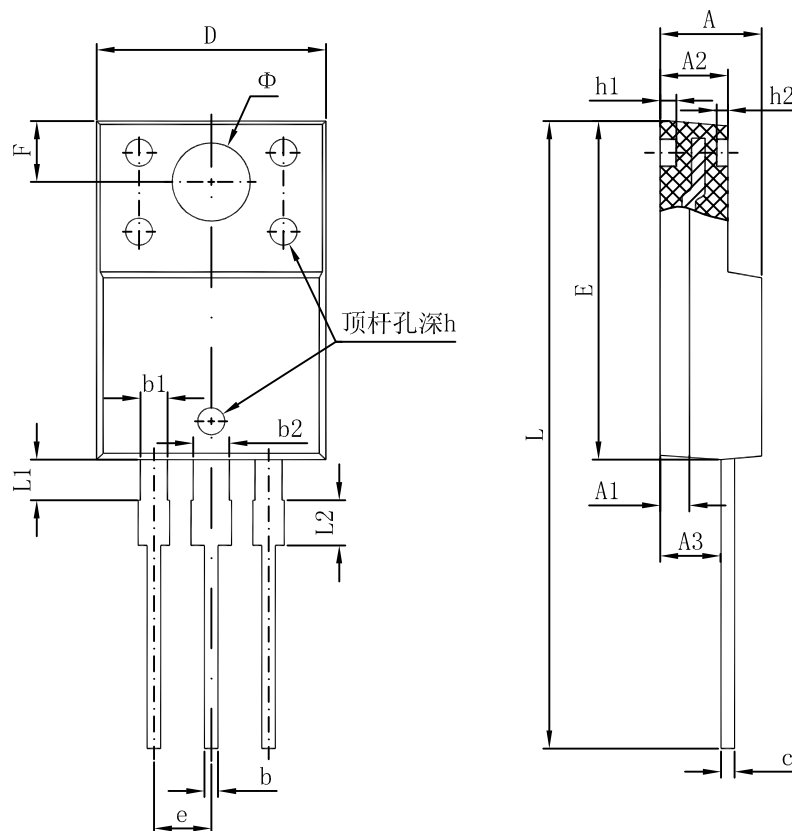


Figure 4: Diode Recovery Test Circuit & Waveform



Package Dimension TO-220F



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.300	4.700	0.169	0.185
A1	1.300 REF.		0.051 REF.	
A2	2.800	3.200	0.110	0.126
A3	2.500	2.900	0.098	0.114
b	0.500	0.750	0.020	0.030
b1	1.100	1.350	0.043	0.053
b2	1.500	1.750	0.059	0.069
c	0.500	0.750	0.020	0.030
D	9.960	10.360	0.392	0.408
E	14.800	15.200	0.583	0.598
e	2.540 TYP.		0.100 TYP.	
F	2.700 REF.		0.106 REF.	
Φ	3.500 REF.		0.138 REF.	
h	0.000	0.300	0.000	0.012
h1	0.800 REF.		0.031 REF.	
h2	0.500 REF.		0.020 REF.	
L	28.000	28.400	1.102	1.118
L1	1.700	1.900	0.067	0.075
L2	1.900	2.100	0.075	0.083



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